

1.5MHZ Zero-Drift CMOS Rail-to-Rail IO Opamp with RF Filter

Features

- Single-Supply Operation from +2.1V ~ +5.5V
- Rail-to-Rail Input / Output
- Gain-Bandwidth Product: 1.5MHz (Typ. @25°C)
- Low Input Bias Current: 20pA (Typ. @25°C)
- Low Offset Voltage: 5uV (Max. @25°C)
- Quiescent Current: 320µA per Amplifier (Typ.)
- Operating Temperature: -40°C ~ +125°C

- Zero Drift: 0.05µV/°C (Max.)
- Embedded RF Anti-EMI Filter
- Small Package:

AD8551 Available in SOT23-5 and SOP-8 Packages AD8552 Available in MSOP-8 and SOP-8 Packages

General Description

The AD855X amplifier is single/dual supply, micro-power, zero-drift CMOS operational amplifiers, the amplifiers offer bandwidth of 1.5MHz, rail-to-rail inputs and outputs, and single-supply operation from 2.1V to 5.5V. AD855X uses chopper stabilized technique to provide very low offset voltage (less than 5µV maximum) and near zero drift over temperature. Low quiescent supply current of 320µA per amplifier and very low input bias current of 20pA make the devices an ideal choice for low offset, low power consumption and high impedance applications. The AD855X offers excellent CMRR without the crossover associated with traditional complementary input stages. This design results in superior performance for driving analog-to-digital converters (ADCs) without degradation of differential linearity.

The AD8551 is available in SOT23-5 and SOP8 packages. And the AD8552 is available in MSOP8 and SOP8 packages. The extended temperature range of -40° C to $+125^{\circ}$ C over all supply voltages offers additional design flexibility.

Applications

- Transducer Application
- Temperature Measurements
- Electronics Scales

Pin Configuration

- Handheld Test Equipment
- Battery-Powered Instrumentation

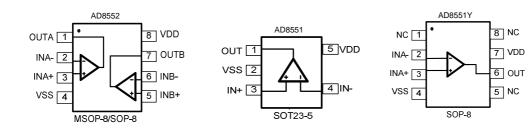


Figure 1. Pin Assignment Diagram



Absolute Maximum Ratings

| Condition | Min | Max | | | |
|---|----------|-----------------------|--|--|--|
| Power Supply Voltage (V _{DD} to Vss) | -0.5V | +7.5V | | | |
| Analog Input Voltage (IN+ or IN-) | Vss-0.5V | V _{DD} +0.5V | | | |
| PDB Input Voltage | Vss-0.5V | +7V | | | |
| Operating Temperature Range | -40°C | +125°C | | | |
| Junction Temperature | +160 | +160°C | | | |
| Storage Temperature Range | -55°C | +150°C | | | |
| Lead Temperature (soldering, 10sec) | +260 | +260°C | | | |
| Package Thermal Resistance (T _A =+25℃) | · | | | | |
| SOP-8, θ _{JA} | 125° | 125°C/W | | | |
| MSOP-8, θ _{JA} | 216° | 216°C/W | | | |
| SOT23-5, θ _{JA} | 190° | 190°C/W | | | |
| ESD Susceptibility | | | | | |
| НВМ | 6K | 6KV | | | |
| MM | 400 | 400V | | | |

Note: Stress greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.



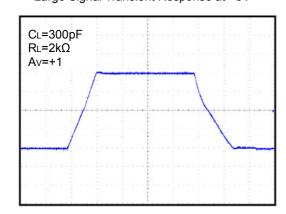
Electrical Characteristics

(V_S = +5V, V_{CM} = +2.5V, V_O = +2.5V, T_A = +25 $^\circ\! \mathbb{C}$, unless otherwise noted.)

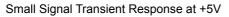
| PARAMETER | CONDITIONS | MIN | ТҮР | MAX | UNITS |
|---|---|-----|-------|-----|----------------|
| INPUT CHARACTERISTICS | | • | | | • |
| Input Offset Voltage (V _{OS}) | | | 1 | 5 | μV |
| Input Bias Current (I _B) | | | 20 | | pА |
| Input Offset Current (I _{OS}) | | | 10 | | pА |
| Common-Mode Rejection Ratio (CMRR) | $V_{CM} = 0V$ to 5V | | 110 | | dB |
| Large Signal Voltage Gain (A _{VO}) | R_L = 10k Ω , V_O = 0.3V to 4.7V | | 145 | | dB |
| Input Offset Voltage Drift ($\Delta V_{OS}/\Delta_T$) | | | 50 | | nV/℃ |
| OUTPUT CHARACTERISTICS | | · | | | |
| Output Voltage High (V _{OH}) | R_L = 100k Ω to - V _S | | 4.998 | | V |
| | R_L = 10k Ω to - V _S | | 4.994 | | V |
| Output Voltage Low (V _{OL}) | R_L = 100k Ω to + V _S | | 2 | | mV |
| | R_L = 10k Ω to + V _S | | 5 | | mV |
| Short Circuit Limit (I _{SC}) | R_L =10 Ω to - V_S | | 43 | | mA |
| Output Current (I _O) | | | 30 | | mA |
| POWER SUPPLY | | | | | |
| Power Supply Rejection Ratio (PSRR) | V _S = 2.5V to 5.5V | | 115 | | dB |
| Quiescent Current (I _Q) | $V_0 = 0V, R_L = 0\Omega$ | | 320 | | μA |
| DYNAMIC PERFORMANCE | | | | | |
| Gain-Bandwidth Product (GBP) | G = +100 | | 1.5 | | MHz |
| Slew Rate (SR) | R _L = 10kΩ | | 0.84 | | V/µs |
| Overload Recovery Time | | | 0.10 | | ms |
| NOISE PERFORMANCE | | | • | • | |
| Voltage Noise (e _n p-p) | 0Hz to 10Hz | | 0.81 | | μV_{P-P} |
| Voltage Noise Density (e _n) | f = 1kHz | | 49 | | nV/\sqrt{Hz} |

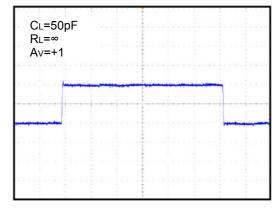


Typical Performance characteristics

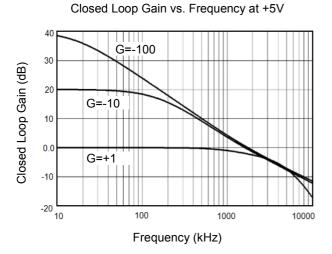


Time(4µs/div)





Time(4µs/div)



Large Signal Transient Response at +5V

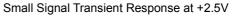
C∟=300pF R∟=2kΩ A∨=+1

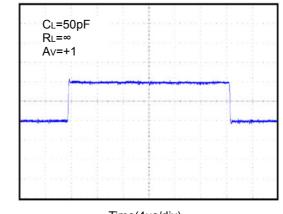
Output Voltage (500mV/div)

Output Voltage (50mV/div)

Large Signal Transient Response at +2.5V

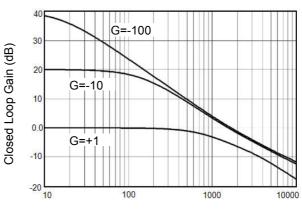
Time(2µs/div)





Time(4µs/div)

Closed Loop Gain vs. Frequency at +2.5V



Frequency (kHz)

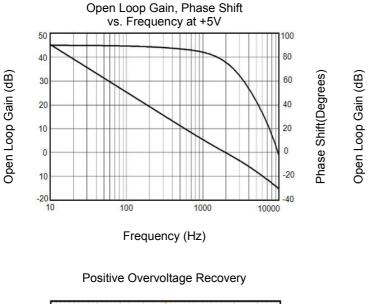
Output Voltage (50mV/div)

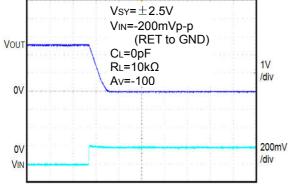
Output Voltage (1V/div)



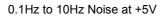
AD8551/52

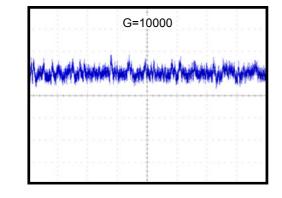
Typical Performance characteristics



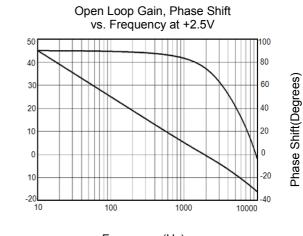


Time (4µs/div)

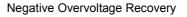


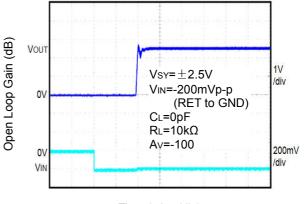


Time (10s/div)



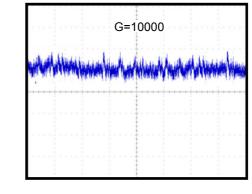
Frequency (Hz)





Time (40µs/div)





Noise (2mv/div)

5

Time (10s/div)

Noise (2mv/div)



Application Note

Size

AD855X series op amps are unity-gain stable and suitable for a wide range of general-purpose applications. The small footprints of the AD855X series packages save space on printed circuit boards and enable the design of smaller electronic products.

Power Supply Bypassing and Board Layout

AD855X series operates from a single 2.1V to 5.5V supply or dual $\pm 1.05V$ to $\pm 2.75V$ supplies. For best performance, a 0.1μ F ceramic capacitor should be placed close to the V_{DD} pin in single supply operation. For dual supply operation, both V_{DD} and V_{SS} supplies should be bypassed to ground with separate 0.1μ F ceramic capacitors.

Low Supply Current

The low supply current (typical 320uA per channel) of AD855X series will help to maximize battery life . They are ideal for battery powered systems

Operating Voltage

AD855X series operate under wide input supply voltage (2.1V to 5.5V). In addition, all temperature speci fications apply from -40 °C to +125 °C. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure operation throughout the single Li-lon battery lifetime

Rail-to-Rail Input

The input common-mode range of AD855X series extends 100mV beyond the supply rails (V_{SS} -0.1V to V_{DD} +0.1V). This is achieved by using complementary input stage. For normal operation, inputs should be limited to this range.

Rail-to-Rail Output

Rail-to-Rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating in low supply voltages. The output voltage of AD855X series can typically swing to less than 5mV from supply rail in light resistive loads (>100k Ω), and 60mV of supply rail in moderate resistive loads (10k Ω).

Capacitive Load Tolerance

The AD855x family is optimized for bandwidth and speed, not for driving capacitive loads. Output capacitance will create a pole in the amplifier's feedback path, leading to excessive peaking and potential oscillation. If dealing with load capacitance is a requirement of the application, the two strategies to consider are (1) using a small resistor in series with the amplifier's output and the load capacitance and (2) reducing the bandwidth of the amplifier's feedback loop by increasing the overall noise gain. Figure 2. shows a unity gain follower using the series resistor strategy. The resistor isolates the output from the capacitance and, more importantly, creates a zero in the feedback path that compensates for the pole created by the output capacitance.

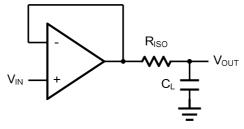


Figure 2. Indirectly Driving a Capacitive Load Using Isolation Resistor

The bigger the R_{ISO} resistor value, the more stable V_{OUT} will be. However, if there is a resistive load R_L in parallel with the capacitive load, a voltage divider (proportional to R_{ISO}/R_L) is formed, this will result in a gain error.

The circuit in Figure 3 is an improvement to the one in Figure 2. R_F provides the DC accuracy by feed-forward the V_{IN} to R_L. C_F



and R_{ISO} serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving the phase margin in the overall feedback loop. Capacitive drive can be increased by increasing the value of C_{F} . This in turn will slow down the pulse response.

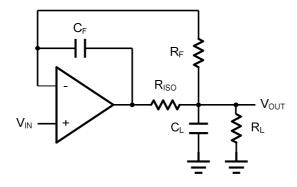


Figure 3. Indirectly Driving a Capacitive Load with DC Accuracy



Typical Application Circuits

Differential amplifier

The differential amplifier allows the subtraction of two input voltages or cancellation of a signal common the two inputs. It is useful as a computational amplifier in making a differential to single-end conversion or in rejecting a common mode signal. Figure 4. shown the differential amplifier using AD855X.

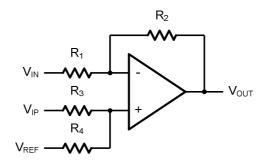


Figure 4. Differential Amplifier

$$V_{\text{OUT}} = \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_4}{R_1} V_{\text{IN}} - \frac{R_2}{R_1} V_{\text{IP}} + \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_3}{R_1} V_{\text{REF}}$$

If the resistor ratios are equal (i.e. $R_1=R_3$ and $R_2=R_4$), then

$$V_{\rm OUT} = \frac{R_2}{R_1} (V_{\rm IP} - V_{\rm IN}) + V_{\rm REF}$$

Low Pass Active Filter

The low pass active filter is shown in Figure 5. The DC gain is defined by $-R_2/R_1$. The filter has a -20dB/decade roll-off after its corner frequency $f_c=1/(2\pi R_3 C_1)$.

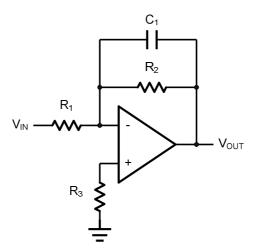


Figure 5. Low Pass Active Filter



Instrumentation Amplifier

The triple AD855X can be used to build a three-op-amp instrumentation amplifier as shown in Figure 6. The amplifier in Figure 6 is a high input impedance differential amplifier with gain of R_2/R_1 . The two differential voltage followers assure the high input impedance of the amplifier.

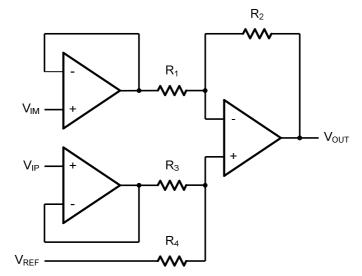


Figure 6. Instrument Amplifier

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Operational Amplifiers - Op Amps category:

Click to view products by HGSEMI manufacturer:

Other Similar products are found below :

 OPA2991IDSGR
 OPA607IDCKT
 007614D
 633773R
 635798C
 635801A
 702115D
 709228FB
 741528D
 NCV33072ADR2G

 SC2903VDR2G
 LM258AYDT
 LM358SNG
 430227FB
 430228DB
 460932C
 AZV831KTR-G1
 409256CB
 430232AB
 LM2904DR2GH

 LM358YDT
 LT1678IS8
 042225DB
 058184EB
 070530X
 714228XB
 714846BB
 873836HB
 MIC918YC5-TR
 TS912BIYDT

 NCS2004MUTAG
 NCV33202DMR2G
 M38510/13101BPA
 NTE925
 SC2904DR2G
 SC358DR2G
 LM358EDR2G
 AZV358MTR-G1

 AP4310AUMTR-AG1
 HA1630D02MMEL-E
 NJM358CG-TE2
 HA1630S01LPEL-E
 LM324AWPT
 HA1630Q06TELL-E
 NJM4558CG-TE2

 AZV358MMTR-G1
 SCY33178DR2G
 NCS4325DR2G
 LM7301SN1T1G
 NJU77806F3-TE1